# 2SD2504

### Silicon NPN epitaxial planar type

#### For low-frequency power amplification

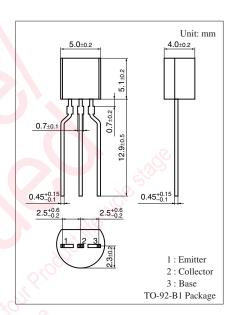
#### ■ Features

- Low collector-emitter saturation voltage V<sub>CE(sat)</sub>
- Large collector current I<sub>C</sub>

#### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	15	V	
Collector-emitter voltage (Base open)	$V_{CEO}$	10	V	
Emitter-base voltage (Collector open)	$V_{EBO}$	10	V	
Collector current	$I_{C}$	5	A	
Peak collector current *	$I_{CP}$	9	A	
Collector power dissipation	$P_{C}$	750	mW	
Junction temperature	$T_{j}$	150	°C	
Storage temperature	T <sub>stg</sub>	-55 to +150	°C	





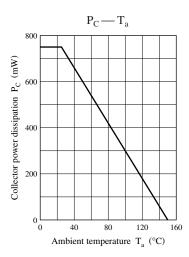
#### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

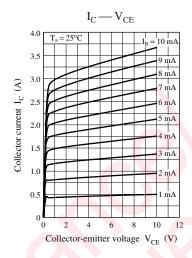
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	$V_{CBO}$	$I_C = 1 \text{ mA}, I_E = 0$	10	J.		V
Collector-emitter voltage (Base open)	$V_{CEO}$	$I_C = 10 \mu\text{A},  I_B = 0$	10			V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = 10 \text{ V}, I_{E} = 0$			0.1	μΑ
Collector-emitter cutoff current (Base open)	$I_{CEO}$	$V_{CE} = 5 \text{ V}, I_{B} = 0$			1.0	μΑ
Emitter-base cutoff current (Collector open)	$I_{EBO}$	$V_{EB} = 5 \text{ V}, I_{E} = 0$			0.1	μΑ
Forward current transfer ratio *	h <sub>FE1</sub>	$V_{CE} = 2 \text{ V}, I_{C} = 0.5 \text{ A}$	300		800	_
	h <sub>FE2</sub>	$V_{CE} = 2 \text{ V}, I_{C} = 2 \text{ A}$	195			
Collector-emitter saturation voltage *	V <sub>CE(sat)</sub>	$I_C = 3 \text{ A}, I_B = 0.1 \text{ A}$		0.28	0.50	V
Transition frequency	$f_T$	$V_{CB} = 6 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		170		MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = 20 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$		45	65	pF
(Common base, input open circuited)						

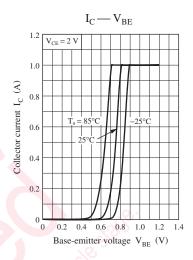
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

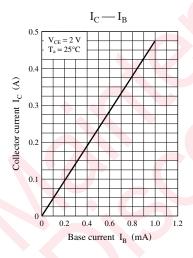
2. \*: Pulse measurement

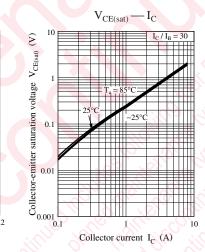
### **Panasonic**

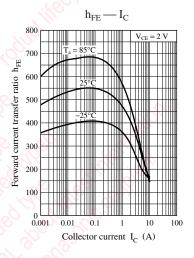


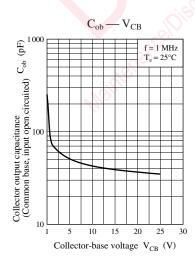












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